

Acoustic and Optical Phonon Field Couplings in Piezoelectric Semiconductors

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Outline

- Elastic Equations for a Cubic Crystal
- Coupled Acoustic and Optical Phonons in Piezoelectric Materials
- Boundary Conditions
- New Results
- Acoustic Dispersion and Anisotropy
- Results
- Summary

Constitutive Stress-Strain Relations

$$\begin{aligned}T_1 &= c_{11}S_1 + c_{12}S_2 + c_{12}S_3, \\T_2 &= c_{12}S_1 + c_{11}S_2 + c_{12}S_3, \\T_3 &= c_{12}S_1 + c_{12}S_2 + c_{11}S_3, \\T_4 &= c_{44}S_4 - e_{14}E_1, \quad T_5 = c_{44}S_5 - e_{14}E_2, \quad T_6 = c_{44}S_6 - e_{14}E_3, \\D_1 &= \epsilon_{11}E_1 + e_{14}S_4, \quad D_2 = \epsilon_{11}E_2 + e_{14}S_5, \quad D_3 = \epsilon_{11}E_3 + e_{14}S_6.\end{aligned}\quad (1)$$

T_I : Stress tensor (in Voigt notation)

S_I : Strain tensor (in Voigt notation)

E_i : Electric field ($i = 1$ for x etc.)

c_{IJ} : Stiffness tensor

ϵ_{ij} : Permittivity tensor

e_{iJ} : Piezoelectric e tensor

Strain and Displacement

$$\begin{aligned} S_1 &= \frac{\partial u_x}{\partial x}, \quad S_2 = \frac{\partial u_y}{\partial y}, \quad S_3 = \frac{\partial u_z}{\partial z}, \\ S_4 &= \frac{\partial u_y}{\partial z} + \frac{\partial u_z}{\partial y}, \quad S_5 = \frac{\partial u_x}{\partial z} + \frac{\partial u_z}{\partial x}, \\ S_6 &= \frac{\partial u_x}{\partial y} + \frac{\partial u_y}{\partial x}. \end{aligned} \quad (2)$$

u_i : Displacement

We assume the in-plane phonon wavevector is directed along the x axis and low frequencies (quasi-static approximation)

$$\begin{aligned} \mathbf{u}(\mathbf{r}, t) &= e^{iq_x x} \mathbf{u}_n(q_x, z), \\ \mathbf{E} &= -\nabla \phi. \end{aligned} \quad (3)$$

and get

$$\begin{aligned} \left(-q_x^2 c_{11} + c_{44} \frac{\partial^2}{\partial z^2} + \rho \omega^2 \right) u_x + i q_x (c_{12} + c_{44}) \frac{\partial u_z}{\partial z} &= 0, \\ \left(-q_x^2 c_{44} + c_{44} \frac{\partial^2}{\partial z^2} + \rho \omega^2 \right) u_y + 2i q_x e_{14} \frac{\partial \phi}{\partial z} &= 0, \\ i q_x (c_{12} + c_{44}) \frac{\partial u_x}{\partial z} + \left(-q_x^2 c_{44} + c_{11} \frac{\partial^2}{\partial z^2} + \rho \omega^2 \right) u_z &= 0, \\ 2i q_x e_{14} \frac{\partial u_y}{\partial z} + \epsilon_{11} \left(q_x^2 - \frac{\partial^2}{\partial z^2} \right) \phi &= 0. \end{aligned} \quad (4)$$

Phonons in a GaAs Slab

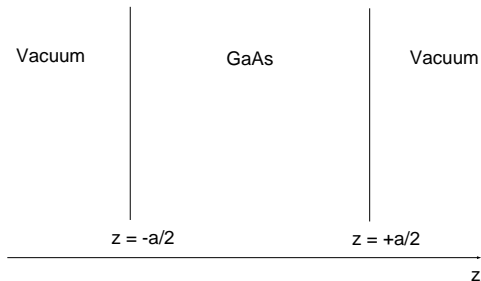


Figure: Schematic drawing of a GaAs slab embedded in semi-infinite layers of vacuum. The slab thickness is a .

Phonons in a GaAs Slab

Two solution types (I and II) exist for $u_x - u_z$ coupled acoustic phonons.
For type I:

$$u_x = \sum_{j=1}^2 A_{x,j} \cos \gamma_j z, \quad u_z = \sum_{j=1}^2 A_{z,j} \sin \gamma_j z, \quad (5)$$

Similarly two solution types (I and II) exist for $u_y - \phi$ coupled acousto-optical phonons.

For type I:

$$\begin{aligned} u_y &= A_{y,1} \cos(\delta_1 z) + A_{y,2} \cosh(\delta_2 z), \\ \phi &= A_{\phi,1} \sin(\delta_1 z) + A_{\phi,2} \sinh(\delta_2 z), \end{aligned} \quad (6)$$

Electric Field

For vacuum the Maxwell-Poisson equation becomes ($|z| > a/2$),

$$-\epsilon_0 \nabla^2 \phi = \epsilon_0 \left(q_x^2 - \frac{\partial^2}{\partial z^2} \right) \phi = 0, \quad (7)$$

and

$$\begin{aligned} \phi(z) &= \phi_+ e^{-|\mathbf{q}_{\parallel}|z} e^{i\mathbf{q}_{\parallel} \cdot \mathbf{r}} \text{ if } z > a/2, \\ \phi(z) &= \phi_- e^{|\mathbf{q}_{\parallel}|z} e^{i\mathbf{q}_{\parallel} \cdot \mathbf{r}} \text{ if } z < -a/2. \end{aligned} \quad (8)$$

Mechanical and Electric Interface Conditions

$$T_{xz}(z = \pm a/2) = 0; T_{zz}(z = \pm a/2) = 0. \quad (9)$$

$$T_{yz}(z = \pm a/2) = c_{44} \frac{\partial u_y}{\partial z} + e_{14} \frac{\partial \phi}{\partial x} \Big|_{z=\pm a/2} = 0, \quad (10)$$

$$\mathbf{E}_{\parallel} \text{ continuous}, \quad (11)$$

$$\mathbf{D}_{\perp} \text{ continuous}. \quad (12)$$

Optical Phonons

Optical phonon modes are determined from the ionic displacement:

$$\mathbf{u}_{ion} = \mathbf{u}_+ - \mathbf{u}_-, \quad (13)$$

and can be found from the Born-Huang equations

$$\mathbf{u}_{ion} = -\sqrt{\frac{\Omega}{m_r}} \frac{\sqrt{\epsilon(0) - \epsilon(\infty)}\omega_{TO}}{\omega^2 - \omega_{TO}^2} \mathbf{E}. \quad (14)$$

Ω : Unit cell volume

m_r : Unit cell reduced mass

Coupled Acousto-Optic Phonon Normalization

$$\int d\mathbf{r} \left[\sqrt{\frac{m_r}{\Omega}} \mathbf{u}_{ion}^*(\mathbf{r}, t) \right] \left[\sqrt{\frac{m_r}{\Omega}} \mathbf{u}_{ion}(\mathbf{r}, t) \right] + \int d\mathbf{r} [\sqrt{\rho} \mathbf{u}^*(\mathbf{r}, t)] [\sqrt{\rho} \mathbf{u}(\mathbf{r}, t)] = \frac{\hbar}{2\omega_n}. \quad (15)$$

ω_n : Phonon mode frequency

Proof I: Coupled $u_y - \phi$ modes cannot exist at the LO phonon frequency in piezoelectric materials

In this case $\epsilon = 0$ and:

$$u_y = A_y e^{iq_x x}, \quad (16)$$

and

$$\phi = (\phi_0 + \phi_1 z) e^{iq_x x}; \quad \phi_0 = \phi_1 = 0. \quad (17)$$

Continuity of the transverse electric field component:

$$\phi_+ = \phi_- = 0. \quad (18)$$

Continuity in the normal electric displacement:

$$A_y = 0. \quad (19)$$

The electric potential ϕ and the phonon u_y component are both zero.

New Result: It is not possible to excite coupled $u_y - \phi$ modes at the LO phonon frequency in piezoelectric materials!

Proof II: Confined coupled acousto-optical $u_y - \phi$ modes cannot exist in piezoelectric media except at certain discrete q_x wavenumber values

A confined phonon mode is characterized by an electric field that vanishes at the slab interfaces (for type I):

$$u_y = A_y \cos\left(\frac{m\pi}{a}z\right) e^{iq_x x}; \quad \phi = A_\phi \sin\left(\frac{m\pi}{a}z\right) e^{iq_x x}, \quad (20)$$

where $m = 2, 4, 6, \dots$

From the elastic equations:

$$\left(-q_x^2 c_{44} - \left(\frac{m\pi}{a}\right)^2 c_{44} + \rho\omega^2\right) A_y + 2iq_x e_{14} \left(\frac{m\pi}{a}\right) A_\phi = 0, \quad (21)$$

and from the Maxwell-Poisson equation:

$$-2iq_x e_{14} \left(\frac{m\pi}{a}\right) A_y + \epsilon_{11} \left(q_x^2 + \left(\frac{m\pi}{a}\right)^2\right) A_\phi = 0. \quad (22)$$

Proof II...

Hence the possible mode frequencies are

$$\omega_m = \sqrt{\frac{c_{44}}{\rho}} \left[q_x^2 + \left(\frac{m\pi}{a} \right)^2 + \frac{4q_x^2 e_{14}^2 \left(\frac{m\pi}{a} \right)^2}{\epsilon_{11} c_{44} \left(q_x^2 + \left(\frac{m\pi}{a} \right)^2 \right)} \right]^{1/2}. \quad (23)$$

Continuity in the transverse electric field and normal displacement yield $\phi_+ = 0$ and

$$A_\phi = \frac{iq_x e_{14}}{\epsilon_{11} (-1)^{m/2} \left(\frac{m\pi}{a} \right)} A_y. \quad (24)$$

Combining Eqs. (22) and (24):

$$2(-1)^{m/2} \left(\frac{m\pi}{a} \right)^2 = q_x^2 + \left(\frac{m\pi}{a} \right)^2, \quad (25)$$

New Result: Possible only at certain discrete q_x values, $\{q_{x,m}\}$!

Degree of anisotropy for GaAs

$$\alpha = \left| \frac{\frac{c_{11}-c_{12}}{2} - c_{44}}{c_{44}} \right| = 45\% . \quad (26)$$

Dispersion I

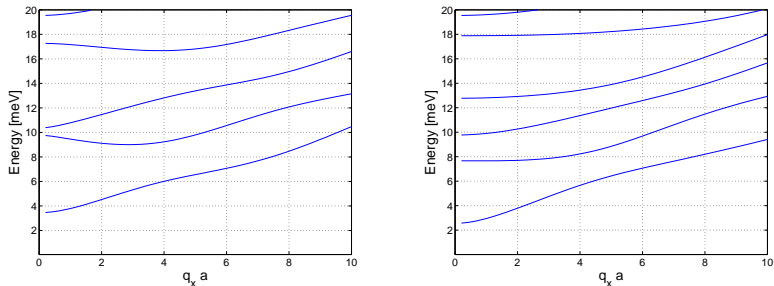


Figure: Dispersion relations for the coupled $u_x - u_z$ acoustic phonon modes of a 2 nm GaAs slab. (Left plot) GaAs and (right plot) GaAs but using the isotropic assumption: $c_{44} = \frac{c_{11} - c_{12}}{2} = 3.25 \cdot 10^{10}$ Pa. The first axis is $q_x a$ and the second axis the phonon band energy in meV.

Dispersion II

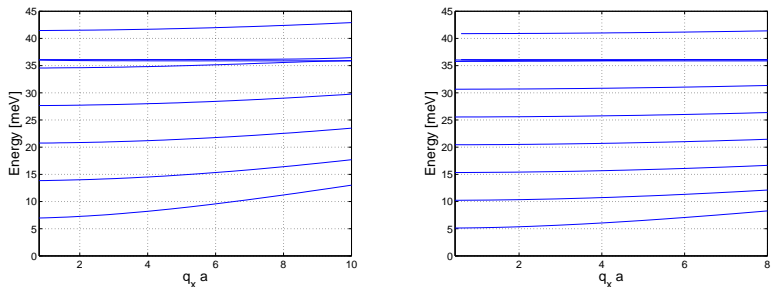


Figure: Dispersion relations for the coupled $u_y - u_{ion}$ acousto-optical phonon modes of a 2 nm GaAs slab. (Left plot) GaAs including piezoelectricity and anisotropy and (right plot) GaAs but using the isotropic non-piezoelectric assumption: $c_{44} = \frac{c_{11} - c_{12}}{2} = 3.25 \cdot 10^{10}$ Pa and $e_{14} = 0$.

Conclusion

- New model for coupled acousto-optic phonons in zincblende crystals
- Pure $u_x - u_z$ acoustic phonon modes exist
- Pure $u_y - u_{ion}$ acousto-optic phonon modes exist
- Proof 1: Coupled $u_y - u_{ion}$ modes cannot exist at the LO phonon frequency in piezoelectric materials
- Proof 2: Confined coupled acousto-optical $u_y - u_{ion}$ modes cannot exist in piezoelectric media except at certain discrete q_x wavenumber values